# 74AUP2G241

# Low-power dual buffer/line driver; 3-state

Rev. 9 — 1 December 2020

Product data sheet

## 1. General description

The 74AUP2G241 provides a dual non-inverting buffer/line driver with 3-state outputs. The 3-state outputs are controlled by the output enable inputs 10E and 20E. A HIGH level at pin 10E causes output 1Y to assume a high-impedance OFF-state. A LOW level at pin 20E causes output 2Y to assume a high-impedance OFF-state.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This device has an input-disable feature, which allows floating input signals. The input 1A is disabled when the output enable input  $1\overline{OE}$  is HIGH. The input 2A is disabled when the output enable input 2OE is LOW.

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- · Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- · Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- · Input-disable feature allows floating input conditions
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G241DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G241GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74AUP2G241GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116
74AUP2G241GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203

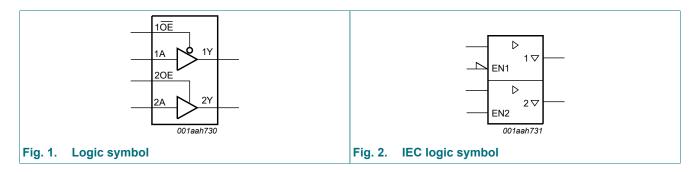
# 4. Marking

Table 2. Marking codes

Type number	Marking code[1]
74AUP2G241DC	p41
74AUP2G241GT	p41
74AUP2G241GN	p1
74AUP2G241GS	p1

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

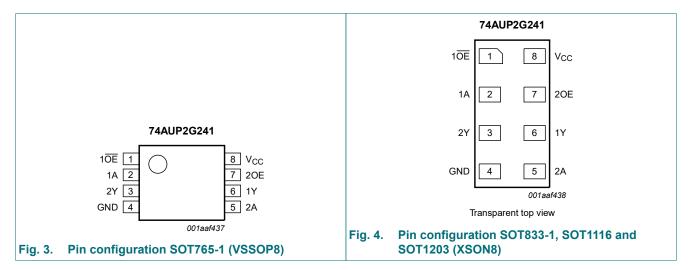
# 5. Functional diagram



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# 6. Pinning information

## 6.1. Pinning



## 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
1 <del>OE</del>	1	output enable input 1 <del>OE</del> (active LOW)
1A, 2A	2, 5	data input
1Y, 2Y	6, 3	data output
GND	4	ground (0 V)
20E	7	output enable input 2OE (active HIGH)
V <sub>CC</sub>	8	supply voltage

# 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ Z = high-impedance \ OFF-state.$ 

-		Output	Input		Output	
1 <del>OE</del>	1A	1Y	2OE 2A		2Y	
L	L	L	Н	L	L	
L	Н	Н	Н	Н	Н	
Н	Х	Z	L	Х	Z	

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# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb}$ = -40 °C to +125 °C [2]	-	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

**Table 6. Operating conditions** 

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

## 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.70V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.65V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
$V_{IL}$	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.30V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V

<sup>[2]</sup> For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: Ptot derates linearly with 3.1 mW/K above 68 °C.

For SOT1116 (XSON8) package: Ptot derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package: Ptot derates linearly with 3.6 mW/K above 81 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.72	-	-	V
		$I_O = -4.0 \text{ mA}$ ; $V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	$I_O = 20 \mu\text{A};  V_{CC} = 0.8 \text{V}  \text{to}  3.6 \text{V}$	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current		_	_	±0.1	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
Δl <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI <sub>CC</sub>	additional supply current	data input; $V_1 = V_{CC} - 0.6 \text{ V}$ ; $I_0 = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	] -	-	40	μA
		$1\overline{OE}$ and 2OE input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; [10 = 0 A; V <sub>CC</sub> = 3.3 V]	1 -	-	110	μA
		all inputs; $V_I$ = GND to 3.6 V; $1\overline{OE}$ = $V_{CC}$ ; [2 2OE = GND; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1	μA
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	0.6	-	pF
Co	output capacitance	output enabled; V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF
		output disabled; $V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_{O} = \text{GND or } V_{CC}$	-	1.5	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.70V <sub>CC</sub>	-	_	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.65V <sub>CC</sub>	_	_	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	_	_	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	_	0.30V <sub>CC</sub>	V
IL.	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	_	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-		0.307	V
		V <sub>CC</sub> = 3.0 V to 3.6 V			0.1	1

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μA
l <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	1] -	-	50	μΑ
		$1\overline{OE}$ and 2OE input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	1] -	-	120	μΑ
		all inputs; $V_I$ = GND to 3.6 V; $1\overline{OE}$ = $V_{CC}$ ; 2OE = GND; $V_{CC}$ = 0.8 V to 3.6 V	2] -	-	1	μΑ
T <sub>amb</sub> = -	40 °C to +125 °C	,				
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.75V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.70V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.25V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V

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Symbol	mbol Parameter Conditions			Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V		V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V		0.6V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V		0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V		1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V		1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V		1.67	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V		2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V		2.30	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V		-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V		-	-	0.33V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V		-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V		-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V		-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V		-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V		-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V		-	-	0.50	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V		-	-	±0.75	μΑ
l <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V		-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$		-	-	±0.75	μΑ
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$ to 0.2 V		-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V		-	-	1.4	μΑ
ΔI <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC}$ - 0.6 V; $I_O = 0$ A; $V_{CC} = 3.3$ V	[1]	-	-	75	μΑ
		$1\overline{OE}$ and 2OE input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	[1]	-	-	180	μΑ
		all inputs; $V_I$ = GND to 3.6 V; $1\overline{OE}$ = $V_{CC}$ ; 2OE = GND; $V_{CC}$ = 0.8 V to 3.6 V	[2]	-	-	1	μΑ

One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND. To show  $I_{CC}$  remains very low when the input-disable feature is enabled.

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# 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions	T,	<sub>amb</sub> = 25	°C	T <sub>ar</sub> -40 °C t	<sub>nb</sub> = o +85 °C	T <sub>ar</sub> -40 °C to	<sub>nb</sub> = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F									
$t_{pd}$	propagation	nA to nY; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	20.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.2	4.8	1.7	6.1	1.7	6.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t <sub>en</sub>	enable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [3]								
		V <sub>CC</sub> = 0.8 V	-	69.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.1	6.1	11.8	2.9	13.9	2.9	15.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.5	4.2	6.6	2.3	7.7	2.3	8.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	3.4	5.1	2.0	6.2	2.0	6.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	2.6	3.7	1.7	4.5	1.7	5.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.4	3.1	1.7	3.5	1.7	3.9	ns
		2OE to 2Y; see Fig. 7 [3]								
		V <sub>CC</sub> = 0.8 V	-	71.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.8	6.2	12.4	2.6	13.6	2.6	13.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.2	6.9	2.2	7.4	2.2	7.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.3	5.3	1.7	5.9	1.7	6.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	2.4	3.6	1.4	3.8	1.4	4.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.0	2.9	1.2	3.2	1.2	3.4	ns
t <sub>dis</sub>	disable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [4]								
		V <sub>CC</sub> = 0.8 V	_	14.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.7	4.3	6.5	2.7	7.3	2.7	8.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	3.2	4.4	2.1	5.1	2.1	5.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.0	4.3	2.0	5.0	2.0	5.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.2	2.9	1.4	3.3	1.4	4.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.5	3.2	1.7	3.4	1.7	3.9	ns
		20E to 2Y; see Fig. 7 [4]								
		V <sub>CC</sub> = 0.8 V	-	10.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.6	4.2	6.2	2.9	6.4	2.9	6.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	3.2	4.4	2.2	4.6	2.2	4.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	3.1	4.4	1.7	4.6	1.7	4.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	2.4	3.2	1.4	3.4	1.4	3.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	2.8	3.6	1.2	3.7	1.2	3.8	ns

Symbol	Parameter	Conditions	Т	<sub>amb</sub> = 25	°C	T <sub>ar</sub> -40 °C t	<sub>nb</sub> = o +85 °C	T <sub>ar</sub>	<sub>nb</sub> = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 10	pF									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	24.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t <sub>en</sub>	enable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [3]								
		V <sub>CC</sub> = 0.8 V	-	73.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	6.9	13.5	3.4	15.8	3.4	17.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.8	7.7	2.2	8.6	2.2	9.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.9	5.8	1.9	6.8	1.9	7.4	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	3.2	4.3	1.7	5.3	1.7	5.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	3.0	3.9	1.7	4.3	1.7	4.8	ns
		20E to 2Y; see Fig. 7 [3]								
		V <sub>CC</sub> = 0.8 V	-	75.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	7.1	14.1	3.0	15.4	3.0	15.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.8	8.0	2.1	8.3	2.1	8.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.8	3.9	5.9	1.7	6.5	1.7	6.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	2.9	4.2	1.4	4.5	1.4	4.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	2.6	3.6	1.3	3.8	1.3	4.0	ns
t <sub>dis</sub>	disable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [4]								
		V <sub>CC</sub> = 0.8 V	-	32.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.4	5.4	7.9	3.4	8.8	3.4	9.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.1	5.5	2.2	6.2	2.2	7.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	4.2	5.6	1.9	6.3	1.9	7.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.0	3.8	1.7	4.5	1.7	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	3.8	4.8	1.7	5.0	1.7	5.6	ns
		20E to 2Y; see Fig. 7 [4]								
		V <sub>CC</sub> = 0.8 V	-	12.2	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.5	5.3	7.6	3.3	7.9	3.3	7.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.1	5.6	2.1	5.7	2.1	5.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.4	4.2	5.7	1.7	5.8	1.7	6.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.9	3.2	4.1	1.4	4.3	1.4	4.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.4	4.1	5.0	1.3	5.2	1.3	5.3	ns

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 15	pF									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	27.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t <sub>en</sub>	enable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [3]								
		V <sub>CC</sub> = 0.8 V	-	77.5	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.0	7.7	15.2	3.7	17.6	3.7	19.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.3	8.4	2.5	9.8	2.5	10.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	4.4	6.5	2.1	7.7	2.1	8.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.6	5.0	2.0	6.1	2.0	6.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	4.5	1.9	4.9	1.9	5.5	ns
		20E to 2Y; see Fig. 7 [3]								
		V <sub>CC</sub> = 0.8 V	-	79.2	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	7.8	15.8	3.3	17.1	3.3	17.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.4	8.8	2.9	9.4	2.9	9.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	4.3	6.7	2.0	7.3	2.0	7.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	3.4	4.8	1.7	5.2	1.7	5.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.6	3.1	4.3	1.5	4.5	1.5	4.7	ns
t <sub>dis</sub>	disable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [4]								
		V <sub>CC</sub> = 0.8 V	-	60.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.3	6.5	9.2	3.7	10.3	3.7	11.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.0	6.5	2.5	7.4	2.5	8.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	5.3	6.6	2.1	7.4	2.1	8.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.8	4.9	2.0	5.1	2.0	6.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.9	5.0	6.2	1.9	6.6	1.9	7.4	ns
		20E to 2Y; see Fig. 7 [4]								
		V <sub>CC</sub> = 0.8 V	_	14.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.3	6.4	8.5	3.7	9.3	3.7	9.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.0	6.6	2.5	6.9	2.5	7.0	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.1	5.4	6.6	2.0	7.4	2.0	7.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.4	4.0	5.0	1.7	5.1	1.7	5.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	3.2	5.3	6.2	1.5	6.7	1.5	6.9	ns

## Low-power dual buffer/line driver; 3-state

Symbol Parameter		Conditions	T,	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 30	pF									
t <sub>pd</sub> propagation		nA to nY; see Fig. 5 [2]								
delay	delay	V <sub>CC</sub> = 0.8 V	-	37.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.8	9.5	19.0	4.4	21.6	4.4	24.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.0	2.5	8.3	ns
t <sub>en</sub>	enable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [3]								
		V <sub>CC</sub> = 0.8 V	-	88.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	5.2	9.9	19.8	4.8	22.8	4.8	25.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.8	10.8	3.1	12.6	3.1	14.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	5.6	8.5	2.8	10.2	2.8	11.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.8	6.5	2.6	7.8	2.6	8.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.7	4.6	6.0	2.6	6.9	2.6	7.7	ns
		20E to 2Y; see Fig. 7 [3]								
		V <sub>CC</sub> = 0.8 V	-	90.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.7	10.0	20.4	4.3	22.0	4.3	22.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	6.9	11.3	3.7	12.0	3.7	12.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	5.6	8.6	3.2	9.5	3.2	10.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.3	4.5	6.3	2.9	6.8	2.9	7.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.2	4.2	5.8	2.7	6.4	2.7	6.7	ns
t <sub>dis</sub>	disable time	1 <del>OE</del> to 1Y; see <u>Fig. 6</u> [4]								
		V <sub>CC</sub> = 0.8 V	-	49.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	6.0	9.9	13.3	4.8	14.8	4.8	16.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.4	7.7	9.6	3.1	10.7	3.1	12.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	5.1	8.7	11.1	2.8	12.4	2.8	13.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.6	6.2	7.4	2.6	8.6	2.6	9.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.2	8.7	10.5	2.6	10.8	2.6	13.1	ns
		20E to 2Y; see Fig. 7 [4]								
		V <sub>CC</sub> = 0.8 V	-	51.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	6.0	9.8	13.6	4.7	14.3	4.7	14.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.5	7.7	10.5	3.0	10.7	3.0	11.0	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	5.2	8.8	11.4	2.6	11.5	2.6	11.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.9	6.4	7.4	2.3	9.0	2.3	10.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.5	9.0	10.7	2.2	10.8	2.2	12.0	ns

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#### Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F, 10 pF, 15 p	F and 30 pF								
C <sub>PD</sub>	power	$f = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}[5]$								
	dissipation capacitance	V <sub>CC</sub> = 0.8 V	-	2.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF

- All typical values are measured at nominal V<sub>CC</sub>.
- $t_{\text{pd}}$  is the same as  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$ . [2]
- [3]  $t_{en}^{r}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [4]
- $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

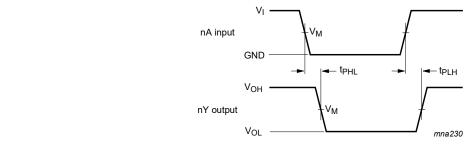
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

## 11.1. Waveforms and test circuit



Measurement points are given in <u>Table 9</u>.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 5. The data input (nA) to output (nY) propagation delays

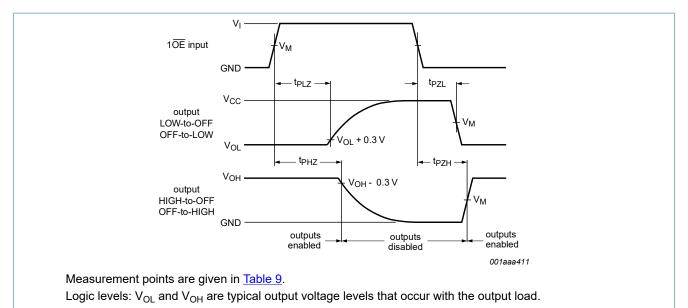


Fig. 6. 3-state enable and disable times

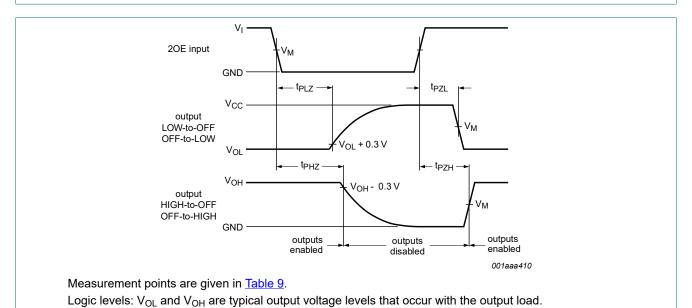
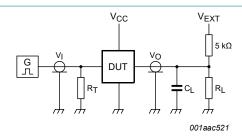


Fig. 7. 3-state enable and disable times

**Table 9. Measurement points** 

Supply voltage	Input			Output			
V <sub>CC</sub>	V <sub>M</sub>	VI	t <sub>r</sub> = t <sub>f</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>	
0.8 V to 1.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> - 0.1 V	
1.65 V to 2.7 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V	
3.0 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V	

#### Low-power dual buffer/line driver; 3-state



Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

#### Fig. 8. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	C <sub>L</sub>   R <sub>L</sub> [1]		t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

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# 12. Package outline

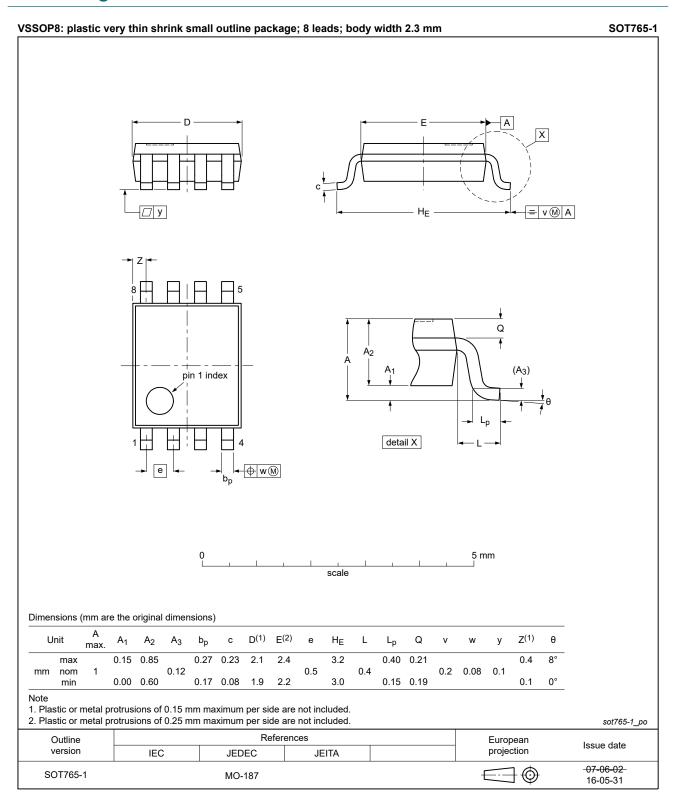


Fig. 9. Package outline SOT765-1 (VSSOP8)

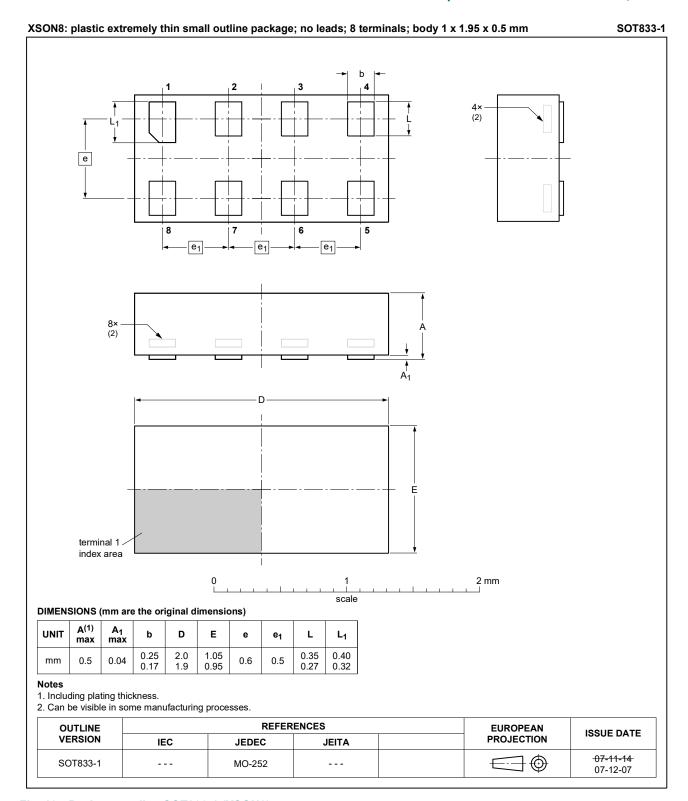


Fig. 10. Package outline SOT833-1 (XSON8)

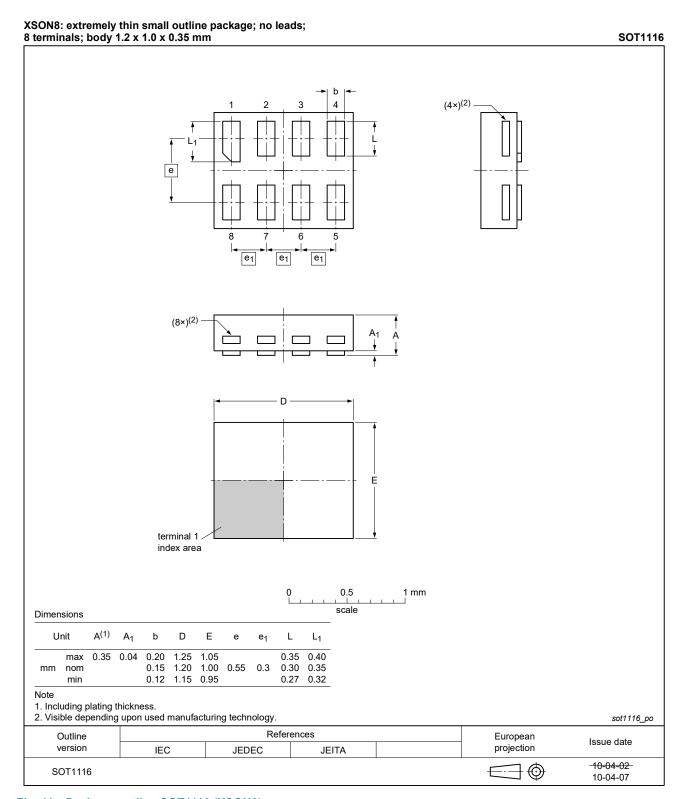


Fig. 11. Package outline SOT1116 (XSON8)

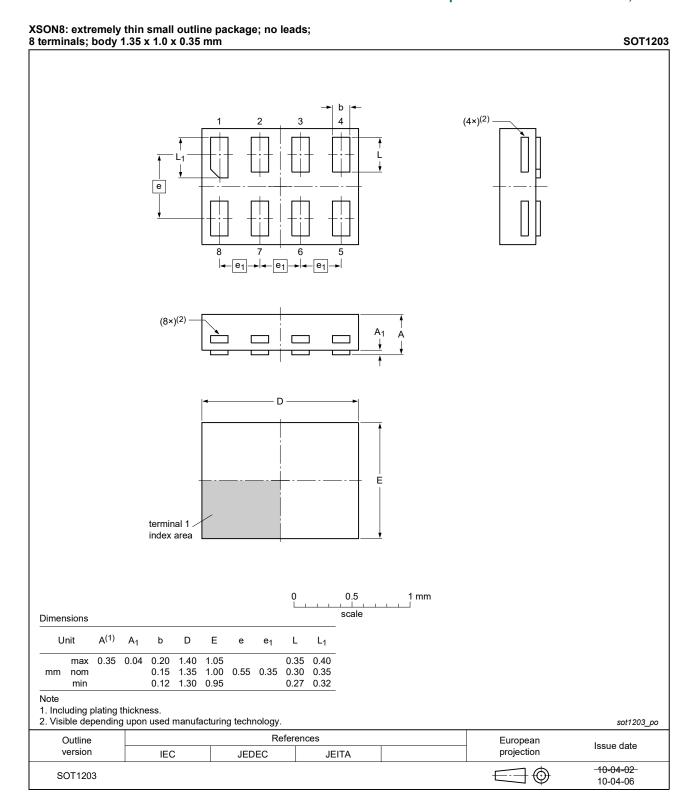


Fig. 12. Package outline SOT1203 (XSON8)

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# 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

## Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP2G241 v.9	20201201	Product data sheet	-	74AUP2G241 v.8			
Modifications:	<ul> <li>Section 8: Derating values for P<sub>tot</sub> total power dissipation have been updated.</li> <li>Type numbers 74AUP2G241GF (SOT1089/XSON8) and 74AUP2G241GM (SOT902-XQFN8) removed.</li> </ul>						
74AUP2G241 v.8	20190321	Product data sheet	-	74AUP2G241 v.7			
Modifications:	of Nexperia. Legal texts h Type number Package outl	f this data sheet has been in ave been adapted to the new r 74AUP2G241GD (XSON& line drawing <u>SOT765-1</u> (VS line drawing SOT902-2 (XG	ew company name 8/SOT996-2) remo SSOP8) updated.				
74AUP2G241 v.7	20130211	Product data sheet	-	74AUP2G241 v.6			
Modifications:	For type num	ber 74AUP2G241GD XSC	N8U has change	d to XSON8.			
74AUP2G241 v.6	20120606	Product data sheet	-	74AUP2G241 v.5			
74AUP2G241 v.5	20111205	Product data sheet	-	74AUP2G241 v.4			
74AUP2G241 v.4	20100913	Product data sheet	-	74AUP2G241 v.3			
74AUP2G241 v.3	20090112	Product data sheet	-	74AUP2G241 v.2			
74AUP2G241 v.2	20080219	Product data sheet	-	74AUP2G241 v.1			
74AUP2G241 v.1	20061012	Product data sheet	-	-			

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## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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